

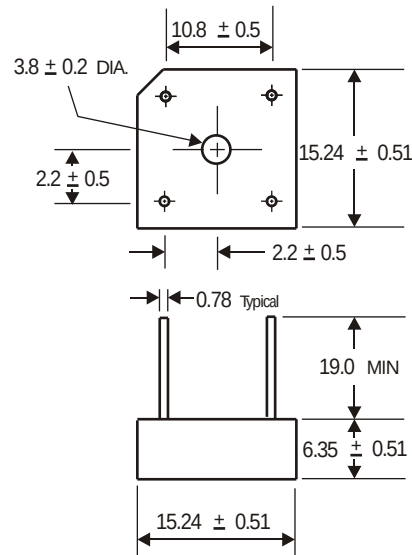


Features

- This series is UL listed under the Recognized Component Index, file number E142814
- High temperature metallurgically bonded internal rectifiers
- Typical I_R less than $.1\mu A$
- The plastic material used carries Underwriters Laboratory flammability recognition 94V-0
- High temperature soldering guaranteed 265°C/10 seconds at 5 lbs (2.3kg) tension

Mechanical Data

Case: Voil-free plastic package
 Terminals: Plated leads solderable per MIL-STD-202, Method 208
 Mounting: Thru hole for #6 screw
 Mounting position: Any
 Weight: 3.8 grams (approx)



Dimensions in millimeters(1mm =0.0394")

Maximum Ratings & Thermal Characteristics

Rating at 25°C ambient temperature unless otherwise specified, Resistive or Inductive load, 60 Hz.
 For Capacitive load derate current by 20%.

Parameter	Symbol	KBPC 1005	KBPC 101	KBPC 102	KBPC 104	KBPC 106	KBPC 108	KBPC 110	unit
Maximum repetitive peak reverse voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS bridge input voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified output current Tc = 50 °C (1)	IF(AV)	3.0							A
Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method)	IFSM	50							A
Rating for fusing (t<8.3ms)	I ² t	10							A ² sec
Typical thermal resistance per element(2)	ReJA	9.4							°C / W
Typical junction capacitance per element(3)	Cj	55							pF
Operating junction and storage temperature range	TJ, TSTG	-55 to + 150							°C

Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified. Resistive or Inductive load, 60Hz.
 For Capacitive load derate by 20 %.

Parameter	Symbol	KBPC 1005	KBPC 101	KBPC 102	KBPC 104	KBPC 106	KBPC 108	KBPC 110	Unit
Maximum instantaneous forward voltage drop per leg at 1.5A	VF	1.1							V
Maximum DC reverse current at rated TA =25°C DC blocking voltage per element TA =100 °C	IR	10 1000							μA

Notes: (1)Mounted on metal chassis.
 (2)Non-repetitive, for t>1ms and < 8.3ms.
 (3)Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3.0 A Single-Phase Silicon Bridge Rectifier

Rectifier Reverse Voltage 50 to 1000V

Rating and Characteristic Curves ($T_A = 25^{\circ}\text{C}$ Unless otherwise noted)

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Fig. 1 Derating Curve for Output Rectified Current

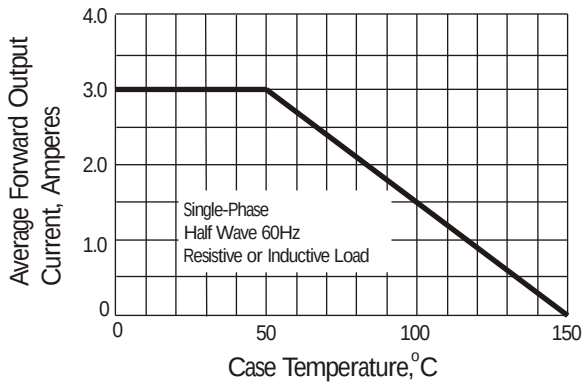


Fig. 2 Maximum Non-repetitive Peak Forward Surge Current

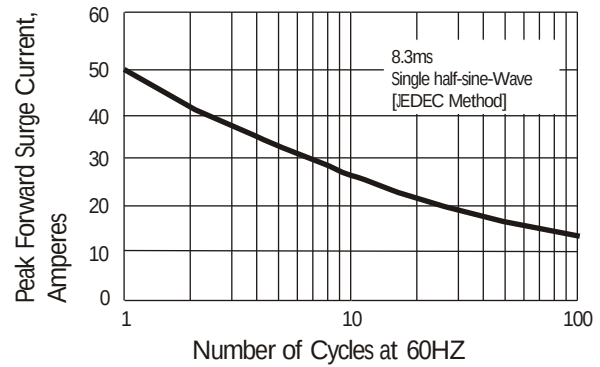


Fig. 3 Typical Instantaneous Forward Characteristics

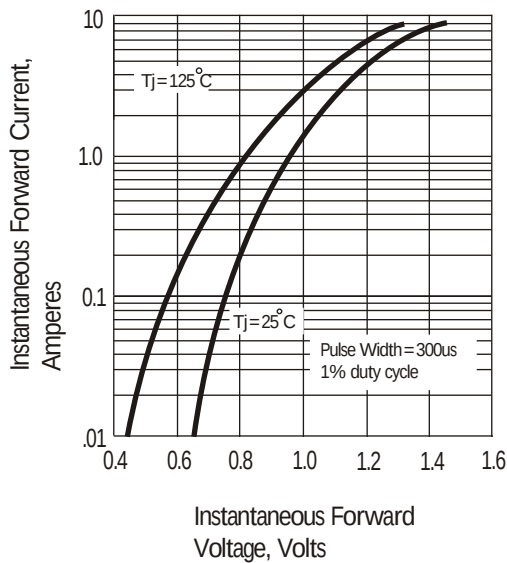


Fig. 4 Typical Reverse Characteristics at $T_J = 25^{\circ}\text{C}$

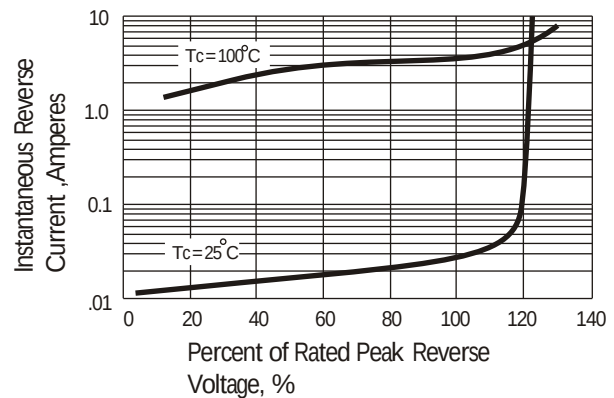


Fig. 5 Typical Junction Capacitance

